



RoHS Compliant 100Gb/s CFP2 ER4 40km Optical Transceiver

OP-MCF2BxxL1SD-40



**Shenzhen Optostar Optoelectronics Co., Ltd
2013. 2(Version 2)**

Product Features

- Supports up to 112Gbps bit rates
- Duplex LC connector
- Hot pluggable
- Operating electrical serial data rate up to 27.952493Gbps
- APD ROSA
- 4 parallel electrical serial interface
- Applicable for 30km SMF connection
- Low power consumption, < 12W
- Digital Diagnostic Monitor Interface
- MDIO Communication Interface
- Compliant with 100GBASE-ER4
- Operating case temperature:
Commerical:0 to 70 °C

Applications

- Local Area Network(LAN)
- Wide Area Network(WAN)
- Switch to router interface

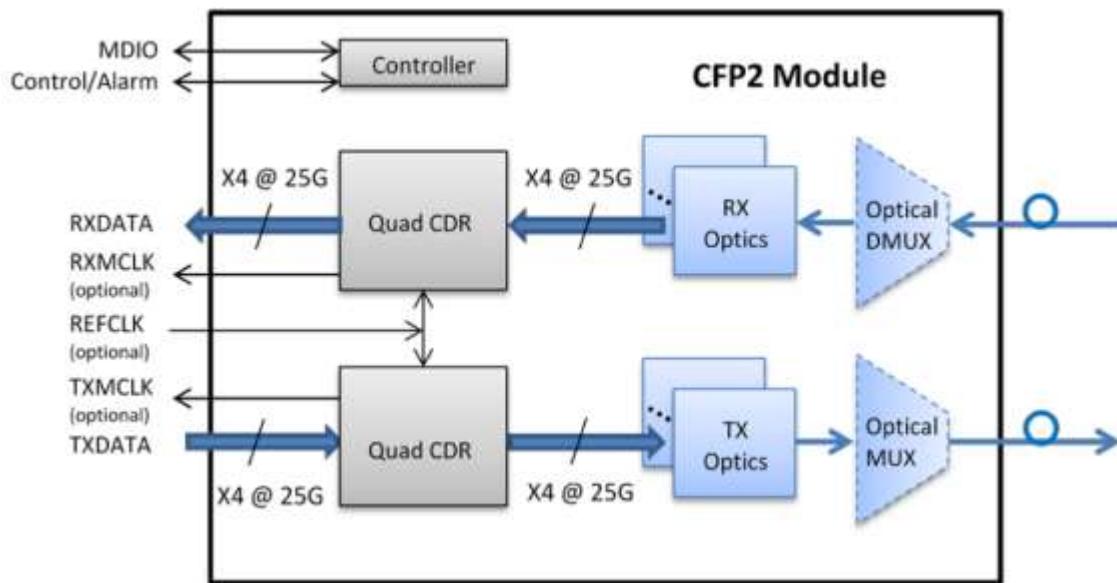
Standards

- Compliant with IEEE 802.3ba
- Compliant with CFP2 MSA hardware specifications
- Compliant with CFP2 MSA management specifications
- Compliant with ITU-T G709/Y.1331
- Compliant with RoHS

Functional Description

OPTOSTAR' OP-MCF2BxxL1SD-40, The 100G CFP2 ER4 optical transceiver integrates the transmit and receive path onto one module. On the transmit side, four lanes of serial data streams are recovered, retimed, and passed on to four laser drivers, which control four electric-absorption modulated lasers (EMLs) with 1296, 1300, 1305, and 1309 nm center wavelengths. The optical signals are then multiplexed into a single-mode fiber through an industry-standard LC connector. On the receive side, four lanes of optical data streams are optically demultiplexed by an integrated optical demultiplexer. Each data stream is recovered by a PIN photodetector and transimpedance amplifier, retimed, and passed on to an output driver. This module features a hot-pluggable electrical interface, low power consumption, and MDIO management interface.

Functional Diagram



Absolute Maximum Ratings

Parameter	Symbol	Min.	Max.	Unit	Note
Supply Voltage	Vcc	-0.5	3.6	V	
Storage Temperature	Ts	-40	85	°C	
Relative Humidity	RH	0	85	%	

Note: Stress in excess of the maximum absolute ratings can cause permanent damage to the transceiver.

Recommended Operating Conditions

Parameter	Symbol	Min.	Typ	Max.	Unit	Note
Data Rate	DR		103.2	112	Gb/s	
Supply Voltage	Vcc	3.14	3.3	3.46	V	
Operating Case Temp.	Tc	0		70	°C	

Electrical Characteristics

(Tested under recommended operating conditions, unless otherwise noted)

Parameter	Symbol	Unit	Min	Typ	Max	Notes	
Voltage Supply Electrical Characteristics							
Supply Current	Tx Section	Icc	A		3.75	1	
	Rx Section						
Power Supply Noise			Vrip		2% DC	1MHz	
Total Dissipation Power	Class1	Pw	W		6	10MHz	
	Class2				9		
	Class3				12		
	Class4				3		

Low Power Mode Dissipation			Plow	W			2		
Inrush Current	Class1	and	I-inrush	mA/usec			100		
Turn-off Current	Class2		I-turnoff	mA/usec	-100				
Inrush Current	Class3	and	I-inrush	mA/usec			200		
Turn-off Current	Class4		I-turnoff	mA/usec	-200				
Different Signal Electrical Characteristics									
Single Ended Data Input Swing				mV	20		525		
Single Ended Data Output Swing				mV	180		385		
Differential Signal Output Resistance				Ω	80		120		
Differential Signal Input Resistance				Ω	80		120		
3.3V LVCMOS Electrical Characteristics									
Input High Voltage			3.3VIH	V	2.0		Vcc+0.3		
Input Low Voltage			3.3VIL	V	-0.3		0.8		
Input Leakage Current			3.3IIN	uA	-10		+10		
Output HighVoltage (IOH=100uA)			3.3VOH	V	Vcc-0.2				
Output Low Voltage (IOL=100uA)			3.3VOL	V			0.2		
Minimum Pulse Width of Control Pin Signal			t_CNTL	us	100				
1.2V LVCMOS Electrical Characteristics									
Input High Voltage			1.2VIH	V	0.84		1.5		
Input Low Voltage			1.2VIL	V	0.3	1.2VIL V	0.36		
Input Leakage Current			1.2IIN	uA	-100		+100		
Output High Voltage			1.2VOH	V	1.0		1.5		
Output Low Voltage			1.2VOL	V	-0.3		0.2		
Output High Current			1.2IOH	mA			-4		
Output Low Current			1.2IOL	mA	+4				
Input Capacitance			Ci	pF			10		

High Speed Electrical Characteristics

Parameter	Symbol	Unit	Min.	Max.	Notes
Impedance	Zd	Ω	90	110	
Frequency		MHz	161.1328125		1/64 of electrical lane rate
Frequency Stability	Δf	ppm	-100	100	For Ethernet
			-20	20	For Telecom
Differential Voltage	VDIFF	mV	400	900	Peak to Peak Differential
Common mode noise (rms)		mV		17.5	
RMS jitter		ps		10	Random Jitter Over frequency band of 10KHZ<f<10MHZ
Clock Duty Cycle		%	40	60	

Optical Characteristics

(Tested under recommended operating conditions, unless otherwise noted)

Parameter	Symbol	Unit	Min	Typ	Max	Notes
Optical Transmitter Characteristics						
Signaling rate, each lane		GBd	25.78125 ±100 ppm		100GBase-ER4	
			27.9525 ±20 ppm		OTU4	
Four Lane Wavelength Range	λ1	nm	1294.53	1295.56	1296.59	
	λ2		1299.02	1300.05	1301.09	
	λ3		1303.54	1304.58	1305.63	
	λ4		1308.09	1309.14	1310.19	
Total launch power		dBm			8.9	100GBase-ER4
Average launch power, each lane	Pavg	dBm	-2.9		2.9	2
Optical modulation amplitude, each lane (OMA)2	OMA	dBm	0.1		4.5	
Difference in launch power between any two lanes (OMA)		dB			3.6	
Extinction ratio	ER	dB	8			100GBase-ER4
Side-mode suppression ratio	SMSR	dB	30			
Transmitter and dispersion penalty, each lane	TDP	dB			2.5	
Optical return loss tolerance		dB			20	
Transmitter reflectance3		dB			-12	
Transmitter eye mask {X1, X2, X3, Y1, Y2, Y3}			{0.25, 0.4, 0.45, 0.25, 0.28, 0.4}		100GBase-ER4	
Optical Receiver Characteristics						
Receive Rate for Each Lane		Gbps		25.78125	27.9525	
Overload Input Optical Power	Pmax	dBm	5.5			3
Average Receive Power for Each Lane	Pin	dBm	-20.9		4.5	4, 5
Receive Power In OMA for Each Lane	PinOMA	dBm			4.5	
Difference in Receive Power in OMA between Any Two Lanes		dBm			4.5	
Receiver Sensitivity in OMA for Each Lane	SOMA	dBm			-21.4	6
Stressed Receiver Sensitivity in OMA for Each Lane		dBm			-17.9	7, 8

Notes:

1. The supply current includes CFP2 module's supply current and test board working current.
2. Average launch power, each lane (min) is informative for 100GBase-LR4, not the principal indicator of signal strength.
3. The receiver shall be able to tolerate, without damage, continuous exposure to an optical input signal having this average power level.
4. The average receive power, each lane (max) for 100GBase-ER4 is larger than the 100BASE-ER4 transmitter value to allow compatibility with 100BASE-LR4 units at short distances.
5. Average receive power, each lane (min) is informative and not the principal indicator of signal strength. A received power below this value cannot be compliant; however, a value above this does not ensure compliance.
6. Receiver sensitivity (OMA), each lane (max) is informative.
7. Measured with conformance test signal at TP3 for BER=10⁻¹²

8. conditions of stressed receiver sensitivity test: vertical eye closure penalty for each lane is 1.8dB; stressed eye J2 jitter for each lane is 0.3UI; stressed eye J9 jitter for each lane is 0.47UI.

Pin Description

The CFP2 connector has 104 pins which are arranged in Top and Bottom rows. The pin map is shown in Table below:

		Bottom		Top	
1	GND	104	GND	104	GND
2	(TX_MCLKn)	103	N.C.	103	N.C.
3	(TX_MCLKp)	102	N.C.	102	N.C.
4	GND	101	GND	101	GND
5	N.C.	100	TX3n	100	TX3n
6	N.C.	99	TX3p	99	TX3p
7	3.3V_GND	98	GND	98	GND
8	3.3V_GND	97	TX2n	97	TX2n
9	3.3V	96	TX2p	96	TX2p
10	3.3V	95	GND	95	GND
11	3.3V	94	N.C.	94	N.C.
12	3.3V	93	N.C.	93	N.C.
13	3.3V_GND	92	GND	92	GND
14	3.3V_GND	91	N.C.	91	N.C.
15	VND IO_A	90	N.C.	90	N.C.
16	VND IO_B	89	GND	89	GND
17	PRG_CNTL1	88	TX1n	88	TX1n
18	PRG_CNTL2	87	TX1p	87	TX1p
19	PRG_CNTL3	86	GND	86	GND
20	PRG_ALRM1	85	TX0n	85	TX0n
21	PRG_ALRM2	84	TX0p	84	TX0p
22	PRG_ALRM3	83	GND	83	GND
23	GND	82	N.C.	82	N.C.
24	RX_DIS	81	N.C.	81	N.C.
25	RX_LOS	80	GND	80	GND
26	MOD_LOPVVR	79	(REFCLKn)	79	(REFCLKn)
27	MOD_AB\$	78	(REFCLKp)	78	(REFCLKp)
28	MOD_RSTn	77	GND	77	GND
29	GLB_ALRMn	76	N.C.	76	N.C.
30	GND	75	N.C.	75	N.C.
31	MDC	74	GND	74	GND
32	MDIO	73	RX3n	73	RX3n
33	PRTA_DR0	72	RX3p	72	RX3p
34	PRTA_DR1	71	GND	71	GND
35	PRTA_DR2	70	RX2n	70	RX2n
36	VND IO_C	69	RX2p	69	RX2p
37	VND IO_D	68	GND	68	GND
38	VND IO_E	67	N.C.	67	N.C.
39	3.3V_GND	66	N.C.	66	N.C.
40	3.3V_GND	65	GND	65	GND
41	3.3V	64	N.C.	64	N.C.
42	3.3V	63	N.C.	63	N.C.
43	3.3V	62	GND	62	GND
44	3.3V	61	RX1n	61	RX1n
45	3.3V_GND	60	RX1p	60	RX1p
46	3.3V_GND	59	GND	59	GND
47	N.C.	58	RX0n	58	RX0n
48	N.C.	57	RX0p	57	RX0p
49	GND	56	GND	56	GND
50	(RX_MCLKn)	55	N.C.	55	N.C.
51	(RX_MCLKp)	54	N.C.	54	N.C.
52	GND	53	GND	53	GND

Pin	Name	I/O	Logic	Description
1	GND			
2	(TX_MCLKn)	O	CML	For optical waveform testing. Not for normal use.
3	(TX_MCLKp)	O	CML	For optical waveform testing. Not for normal use.
4	GND			
5	N.C.			No Connect
6	N.C.			
7	3.3V_GND			3.3V Module Supply Voltage Return Ground, can be separate or tied together with Signal Ground
8	3.3V_GND			
9	3.3V			
10	3.3V			3.3V Module Supply Voltage
11	3.3V			

12	3.3V			
13	3.3V_GND			3.3V Module Supply Voltage Return Ground, can be separate or tied together with Signal Ground
14	3.3V_GND			
15	VND_IO_A	I/O		Module Vendor I/O A. Do Not Connect!
16	VND_IO_B	I/O		Module Vendor I/O A. Do Not Connect!
17	PRG_CNTL1	I	LVC MOS w/ PUR	Programmable Control 1 set over MDIO, MSA Default: TRXIC_RSTn, TX & RX ICs reset, "0": reset, "1" or NC: enabled = not used
18	PRG_CNTL2	I	LVC MOS w/ PUR	Programmable Control 2 set over MDIO, MSA Default: Hardware Interlock LSB, "00": $\leq 3W$, "01": $\leq 6W$, "10": $\leq 9W$, "11" or NC: $\leq 12W$ = not used
19	PRG_CNTL3	I	LVC MOS w/ PUR	Programmable Control 2 set over MDIO, MSA Default: Hardware Interlock LSB, "00": $\leq 3W$, "01": $\leq 6W$, "10": $\leq 9W$, "11" or NC: $\leq 12W$ = not used
20	PRG_ALRM1	O	LVC MOS	Programmable Alarm 1 set over MDIO, MSA Default: HIPWR_ON, "1": module power up completed, "0": module not high powered up
21	PRG_ALRM2	O	LVC MOS	Programmable Alarm 2 set over MDIO, MSA Default: MOD_READY, "1": Ready, "0": not Ready.
22	PRG_ALRM3	O	LVC MOS	Programmable Alarm 3 set over MDIO, MSA Default: MOD_FAULT, fault detected, "1": Fault, "0": No Fault
23	GND			
24	TX_DIS	I	LVC MOS w/ PUR	Transmitter Disable for all lanes, "1" or NC = transmitter disabled, "0" = transmitter enabled
25	RX_LOS	O	LVC MOS	Receiver Loss of Optical Signal, "1": low optical signal, "0": normal condition
26	MOD_LOPWR	I	LVC MOS w/ PUR	Module Low Power Mode. "1" or NC: module in low power (safe) mode, "0": power-on enabled
27	MOD_ABS	O	GND	Module Absent. "1" or NC: module absent, "0": module present, Pull Up Resistor on Host
28	MOD_RSTn	I	LVC MOS w/ PDR	Module Reset. "0" resets the module, "1" or NC = module enabled, Pull Down Resistor in Module
29	GLB_ALRMn	O	LVC MOS	Global Alarm. "0": alarm condition in any MDIO Alarm register, "1": no alarm condition, Open Drain, Pull Up Resistor on Host
30	GND			
31	MDC	I	1.2VCMOS	Management Data Clock (electrical specs as per IEEE Std 802.3ae-2008 and ba-2010)
32	MDIO	I/O	1.2VCMOS	Management Data I/O bi-directional data (electrical specs as per IEEE Std 802.3ae-2008 and ba-2010)
33	PRTADR0	I	1.2VCMOS	MDIO Physical Port address bit 0
34	PRTADR1	I	1.2VCMOS	MDIO Physical Port address bit 1
35	PRTADR2	I	1.2VCMOS	MDIO Physical Port address bit 2
36	VND_IO_C	I/O		Module Vendor I/O C. Do Not Connect!
37	VND_IO_D	I/O		Module Vendor I/O D. Do Not Connect!
38	VND_IO_E	I/O		Module Vendor I/O E. Do Not Connect!
39	3.3V_GND			
40	3.3V_GND			
41	3.3V			3.3V Module Supply Voltage
42	3.3V			
43	3.3V			
44	3.3V			
45	3.3V_GND			
46	3.3V_GND			
47	N.C			No Connect



48	N.C			
49	GND			
50	(RX_MCLKn)	O	CML	
51	(RX_MCLKp)	O	CML	For optical waveform testing. Not for normal use.
52	GND			
53	GND			
54	N.C.			
55	N.C.			
56	GND			
57	RX0p			25 Gbps receiver data; Lane 0
58	RX0n			25 Gbps receiver data bar; Lane 0
59	GND			
60	RX1p			25 Gbps receiver data; Lane 1
61	RX1n			25 Gbps receiver data bar; Lane 1
62	GND			
63	N.C.			
64	N.C.			
65	GND			
66	N.C.			
67	N.C.			
68	GND			
69	RX2p			25 Gbps receiver data; Lane 2
70	RX2n			25 Gbps receiver data bar; Lane 2
71	GND			
72	RX3p			25 Gbps receiver data; Lane 3
73	RX3n			25 Gbps receiver data bar; Lane 3
74	GND			
75	N.C.			
76	N.C.			
77	GND			
78	(REFCLKp)		CML	Module reference clock. No connect.
79	(REFCLKn)		CML	Module reference clock. No connect.
80	GND			
81	N.C.			
82	N.C.			
83	GND			
84	TX0p			25 Gbps transmitter data; Lane 0
85	TX0n			25 Gbps transmitter data bar; Lane 0
86	GND			
87	TX1p			25 Gbps transmitter data; Lane 1
88	TX1n			25 Gbps transmitter data bar; Lane 1
89	GND			
90	N.C.			

91	N.C.							
92	GND							
93	N.C.							
94	N.C.							
95	GND							
96	TX2p			25 Gbps transmitter data; Lane 2				
97	TX2n			25 Gbps transmitter data bar; Lane 2				
98	GND							
99	TX3p			25 Gbps transmitter data; Lane 3				
100	TX3n			25 Gbps transmitter data bar; Lane 3				
101	GND							
102	N.C.							
103	N.C.							
104	GND							

Hardware Control Pins

The CFP2 Module support real-time control functions via hardware pins, listed in the following

Pin	Symbol	Description	I/O	Logic	H	L	Pull-up/down
17	PRG_CNTL1	Programmable Control 1 MSADefault:TRXIC_RS T n , TX&RX ICs reset, “0”:reset,”1”	I	3.3V LVCMOS	per CFP MSA Management Interface Specification		Pull-Up Note1
18	PRG_CNTL2	Programmable Control 2 MSADefault :Hardware Interlock LSB	I	3.3V LVCMOS			Pull-Up Note1
19	PRG_CNTL3	Programmable Control 3 MSA Default:Hardware Interlock MSB	I	3.3V LVCMOS			Pull-Up Note1
26	MOD_LOPW_R	Module Low Power Mode	I	3.3V LVCMOS Low Power Enable Pull-Up	Low Power	Enable	Pull-Up Note1
28	MOD_RSTn	Module Reset(Invert)	I	3.3V LVCMOS	Enable	Reset	Pull-Down Note2

Notes:

1. Pull-Up resistor (4.7KOhm to 10 KOhm) is located within the CFP2 module
2. Pull-Down resistor (4.7KOhm to 10 kOhm) is located within the CFP2 module

Hardware Alarm Pins

The CFP2 Module supports alarm hardware pins listed in the following

Pin	Symbol	Description	I/O	Logic	H	L	Pull-up/down
20	PRG_ALR_M1	Programmable Alarm 1 MSA Default:HIPWR_ON	O	3.3V LVCMOS	Active High per MDIO document		
21	PRG_ALR_M2	Programmable Alarm 2 MSA	O	3.3V LVCMOS			

		default:MOD_READY , Ready State has been reached					
22	PRG_ALR M3	Programmable Alarm 3 MSA Default: MOD_FAULT	O	3.3V LVCMOS			
27	MOD_ABS	Module Absent	O	3.3V LVCMOS	Absent	Present	Pull-Down Note1
25	RX_LOS	Receiver Loss of Signa	O	3.3V LVCMOS	Loss of Signal	OK	

Note:

1.:Pull-Down resistor (<100Ohm) is located within the CFP2 module. Pull-up should be located on the host

Management Interface Pins(MDIO)

The CFP2 Module supports alarm, control and monitor functions via an MDIO bus. The CFP2 MDIO pins are listed in the following:

.	Symbol	Description	I/O	Logic	H	L	Pull-up/down
29	GLB-ALRM n	Global Alarm	I	3.3V LVCMOS	OK	Alarm	
32	MDIO	Management interface bidirectional data	I/O	1.2V LVCMOS			
31	MDC	Management interface clock input	I	1.2V LVCMOS			
33	PRTADDR0	MDIO physical port address bit 0	I	1.2V LVCMOS	Per MDIO		
34	PRTADDR1	MDIO physical port address bit 1	I	1.2V LVCMOS			
35	PRTADDR2	MDIO physical port address bit 2	I	1.2V LVCMOS			

Hardware Signaling Pin Timing Requirements

Timing Parameters for CFP2 hardware Signal Pins are listed in the following:

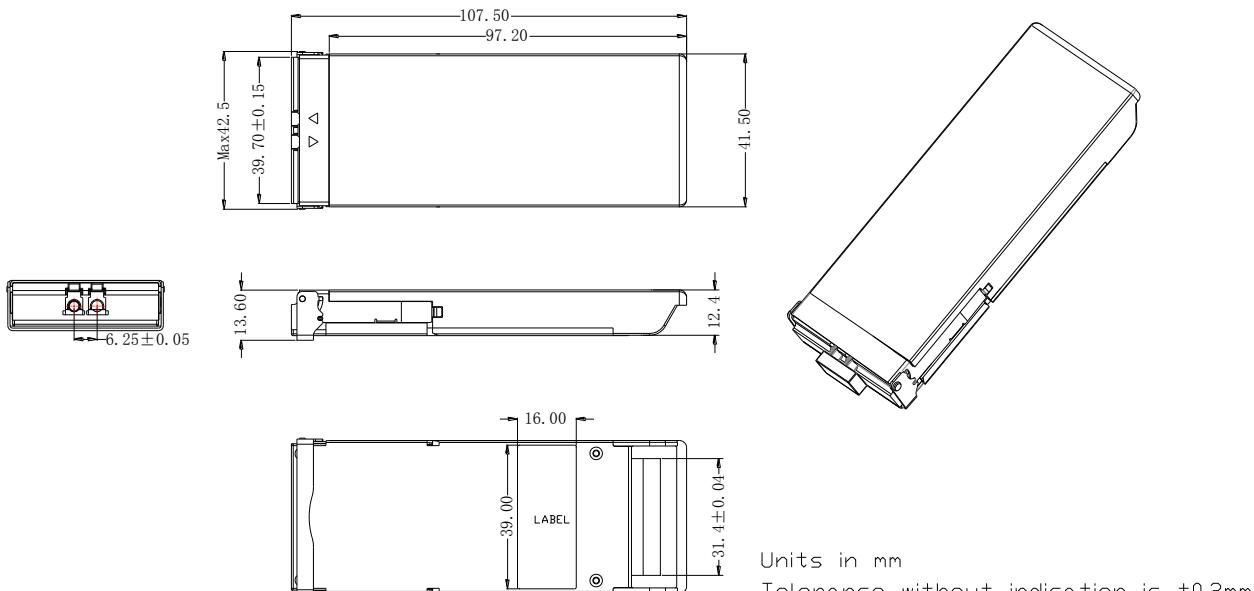
Parameter	Symbol	Unit	Min.	Max.	Notes
Hardware MOD_LOPWR assert	t_MOD_LOPWR_assert	ms		1	
Hardware MOD_LOPWR deassert	t_MOD_LOPWR_deassert	s		60	Stored in NVR register 8072h
Management interface clock period	t_prd	ns	250		MDC is 4 MHz rate or less
Host MDIO setup time	t_setup	ns	10		
Host MDIO hold time	t_hold	ns	10		
CFP2 MDIO delay time	t_delay	ns	0	175	
GLB_ALRM assert time	GLB_ALRMn_assert	ms		150	A logic “OR” of associated MDIO alarm and status registers
GLB_ALRM deassert time	GLB_ALRMn_deassert	ms		150	A logic “OR” of associated MDIO alarm and status registers

Minimum pulse width of control pin signal	t_CNTL	μs	100		
Initialization time from reset	t_initialize	s		2.5	
TX_Disable assert time	t_deassert	μs		100	Transmitter disable, application specific
TX_Disable deassert time1	t_assert	ms		5	Time from Tx Disable pin deasserted until CFP2 module enters the Tx-turn-on state Stored in NVR register 8073h
RX_LOS assert time	t_loss_assert	μs		100	From occurrence of loss of signal to assertion of RX_LOS
RX_LOS deassert time	t_loss_deassert	μs		100	From occurrence of return of signal to deassert of RX_LOS

CFP2 Lane Assignment

Lane	Center Frequency	Center Wavelength	Wavelength Range
L0	231.4 THz	1295.56 nm	1294.53 to 1296.59 nm
L1	230.6 THz	1300.05 nm	1299.02 to 1301.09 nm
L2	229.8 THz	1304.58 nm	1303.54 to 1305.63 nm
L3	229.0 THz	1309.14 nm	1308.09 to 1310.19 nm

Package Dimensions





Ordering Information

Part Number	Description
OP-MCF2BxxL1SD-40	CFP2 100G ER4 40Km 0~70°C

Important Notice

Performance figures, data and any illustrative material provided in this data sheet are typical and must be specifically confirmed in writing by OPTOSTAR before they become applicable to any particular order or contract. In accordance with the OPTOSTAR policy of continuous improvement specifications may change without notice.

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